

SMBG Plastic-Encapsulate Diodes

Super Fast Recovery Rectifier Diode

Features

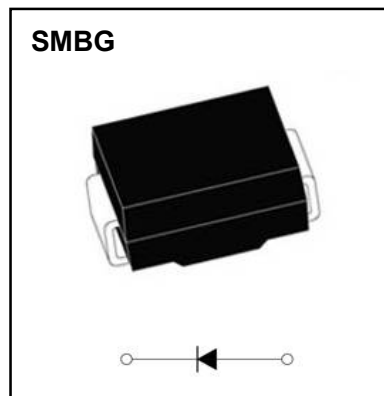
- I_o 3A
- V_{RRM} 50V-600V
- High surge current capability
- Glass passivated chip
- Polarity: Color band denotes cathode

Applications

- Rectifier

Marking

- ES3X
- X : From A To J



Limiting Values (Absolute Maximum Rating)

Item	Symbol	Unit	Test Conditions	ES3							
				A	B	C	D	F	G	H	J
Repetitive Peak Reverse Voltage	V _{RRM}	V		50	100	150	200	300	400	500	600
Maximum RMS Voltage	V _{RMS}	V		35	70	105	140	210	280	350	420
Average Forward Current	I _{F(AV)}	A	60HZ Half-sine wave, Resistance load, T _L =100℃	3.0							
Surge(Non-repetitive)Forward Current	I _{FSM}	A	60Hz Half-sine wave , 1 cycle , Ta =25℃	100							
Junction Temperature	T _J	℃		-55~+150							
Storage Temperature	T _{STG}	℃		-55 ~ +150							

Electrical Characteristics ($T_a=25^{\circ}C$ Unless otherwise specified)

Item	Symbol	Unit	Test Condition		ES3						
					A	B	C	D	F	G	H
Peak Forward Voltage	V _F	V	I _F =3.0A		0.95			1.25		1.7	
Maximum reverse recovery time	t _{rr}	ns	I _F =0.5A,I _R =1.0A,I _{rr} =0.25A		35						
Peak Reverse Current	I _{RRM1}	μA	V _{RM} =V _{RRM}	T _a =25℃	1						
	T _a =100℃			50							
Thermal Resistance(Typical)	R _{θJ-A}	℃/W	Between junction and ambient		47 ¹⁾						
	R _{θJ-L}		Between junction and terminal		12 ¹⁾						

Notes:

Thermal resistance from junction to ambient and from junction to lead mounted on P.C.B. with 0.27" x 0.27" (7.0 mm x 7.0 mm)^{er} copper pad areas

Typical Characteristics

FIG.1: FORWARD CURRENT DERATING CURVE

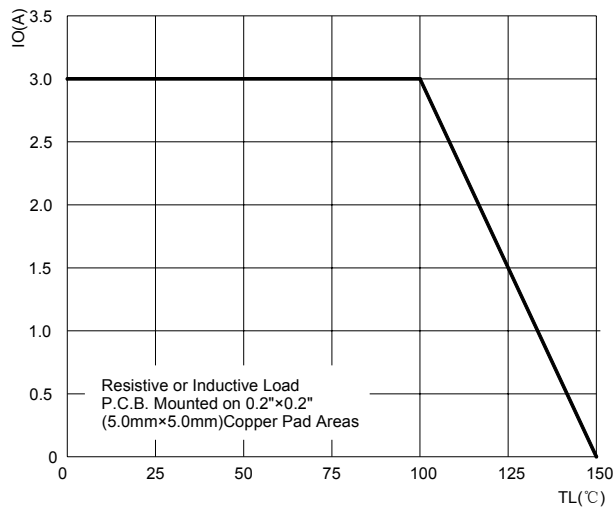


FIG.2: MAXIMUM NON-REPETITIVE FORWARD URGE CURRENT

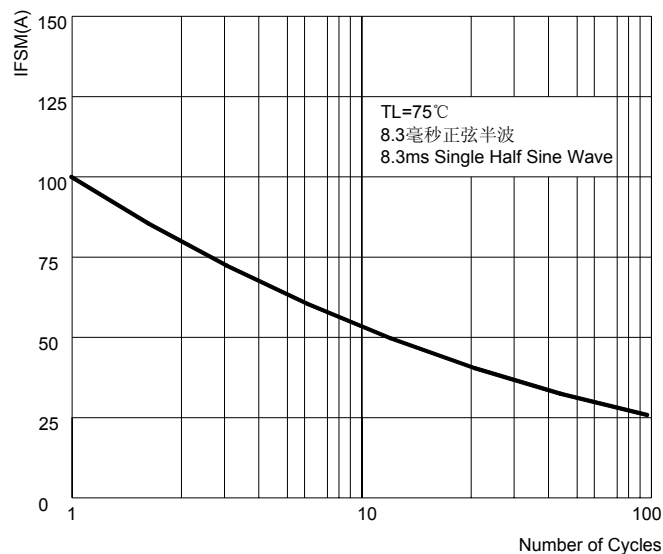


FIG.3: TYPICAL FORWARD CHARACTERISTICS

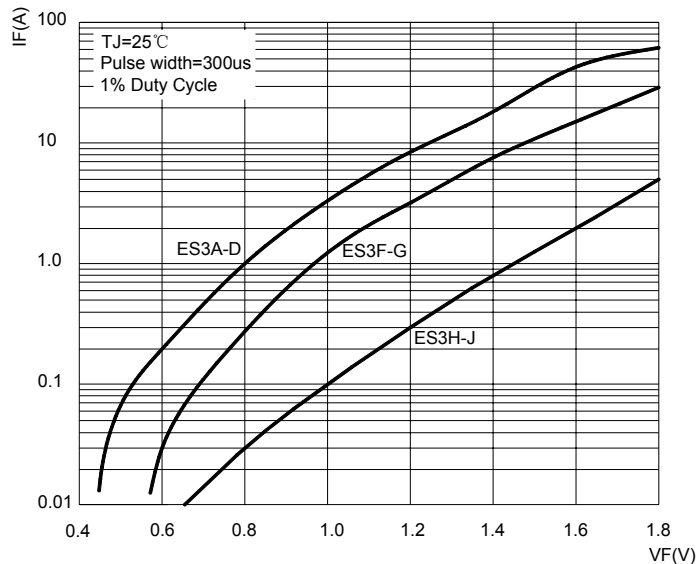


FIG.4: TYPICAL REVERSE CHARACTERISTICS

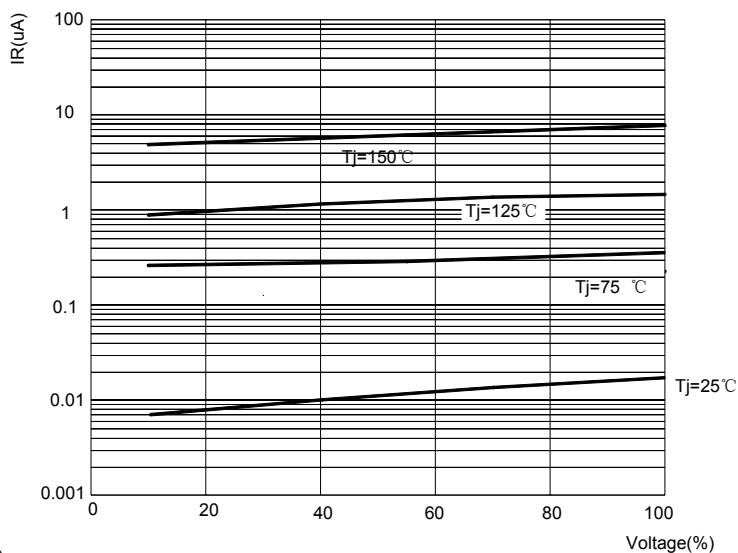
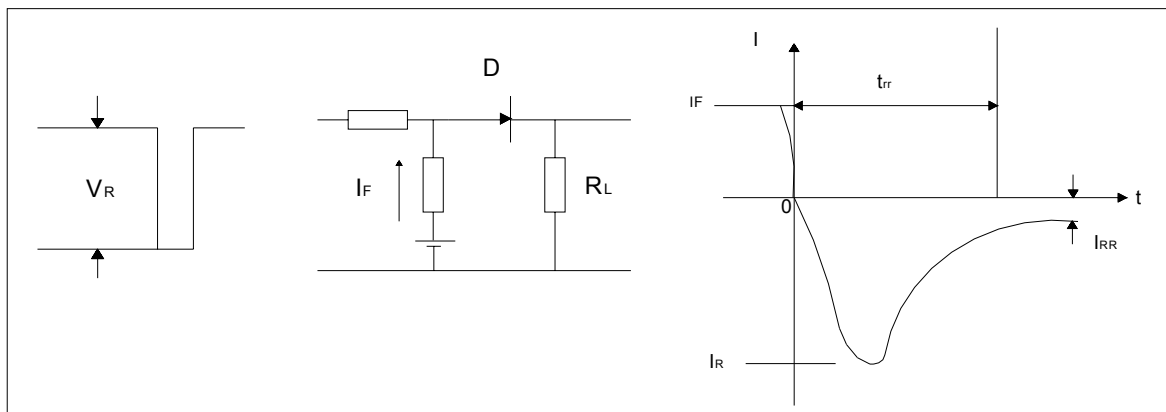
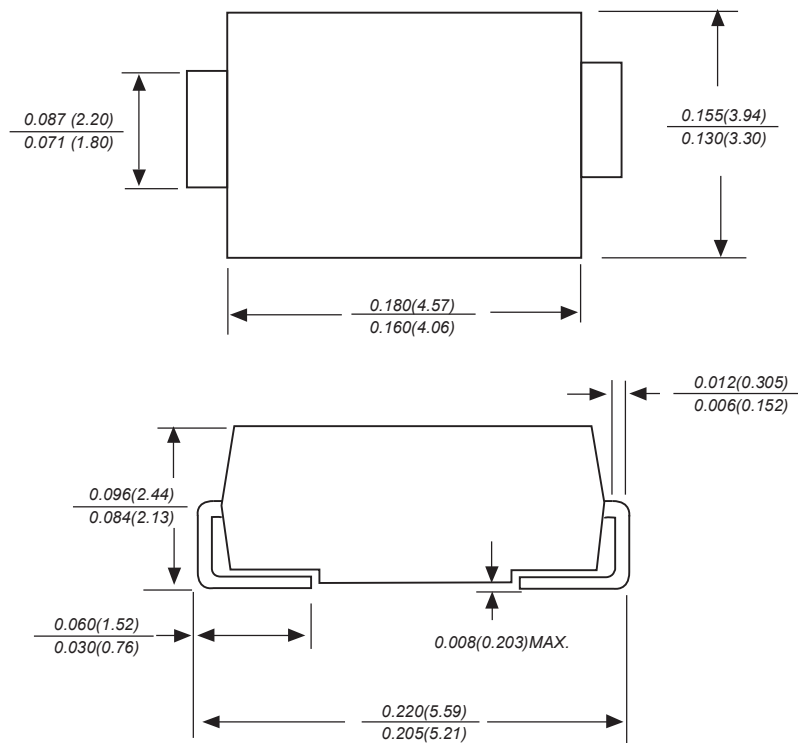


FIG.5: Diagram of circuit and Testing wave form of reverse recovery time

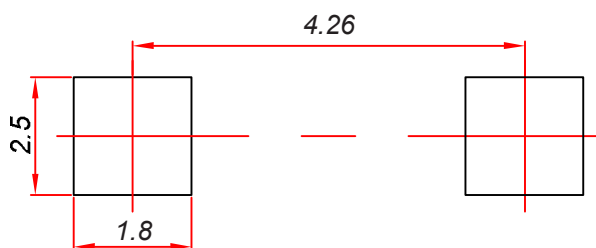


SMBG Package Outline Dimensions



Dimensions in inches and (millimeters)

SMBG Suggested Pad Layout



Note:

1. Controlling dimension: in millimeters.
2. General tolerance: $\pm 0.05\text{mm}$.
3. The pad layout is for reference purposes only.

NOTICE

JSMD reserve the right to make modifications, enhancements, improvements, corrections or other changes without further notice to any product herein. JSMD does not assume any liability arising out of the application or use of any product described herein.

Reel Taping Specifications For Surface Mount Devices–SMBG

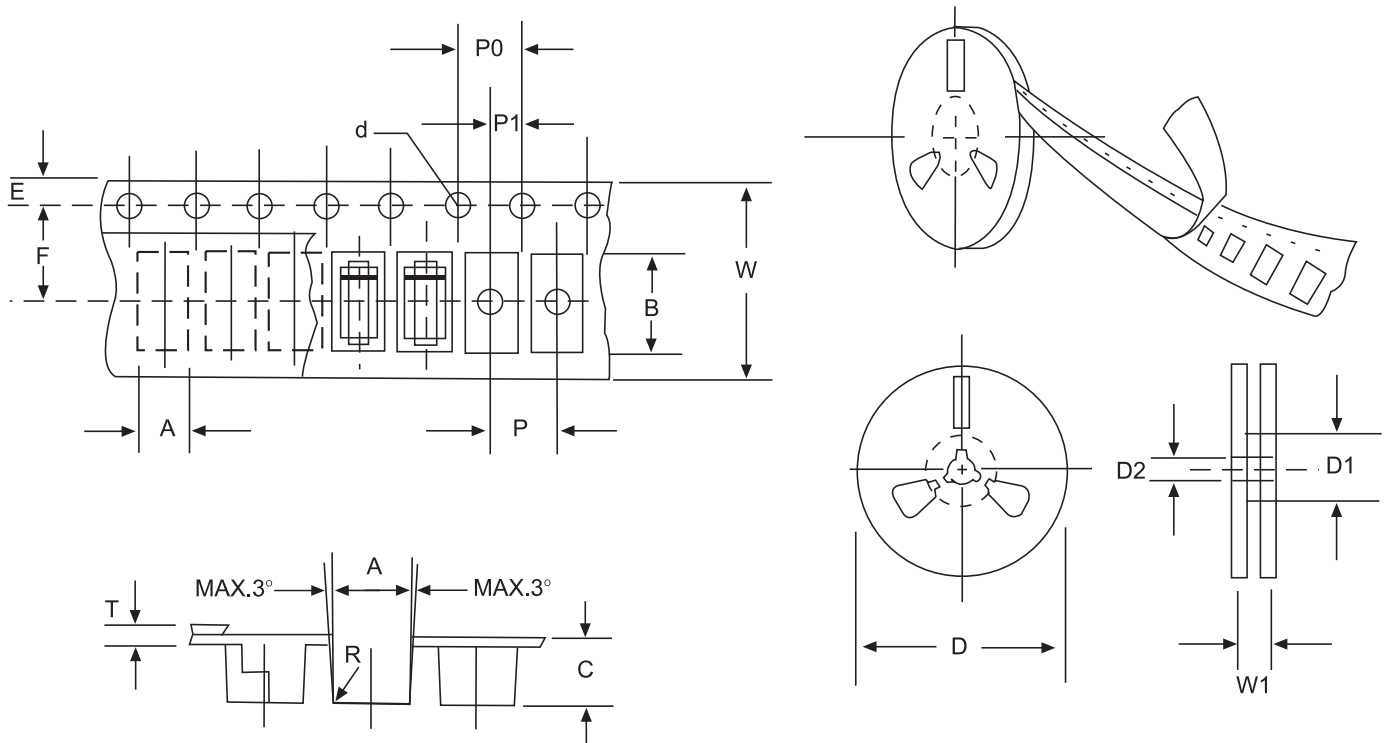


FIG:CONFIGURATION OF AXIAL TAPING

ITEM	SYMBOL	SMBGmm(inch)
Carrier width	A	4.09±0.1(0.161±0.004)
Carrier length	B	5.82±0.1(0.229±0.004)
Carrier depth	C	3.33±0.1(0.131±0.004)
Sprocket hole	d	1.55±0.05(0.061±0.0002)
Reel outside diameter	D	330/178±2.0(13/7.0±0.79)
Reel inner diameter	D1	8.0±0.2(0.315±0.008)
Feed hole diameter	D2	13±0.5(0.512±0.020)
Strocket hole position	E	1.75±0.1(0.069±0.004)
Punch hole position	F	5.65±0.05(0.222±0.002)
Punch hole pitch	P	8.0±0.1(0.315±0.004)
Sprocket hole pitch	P0	4.0±0.1(0.157±0.004)
Embossment center	P1	2.0±0.1(0.079±0.004)
Totall tape thickness	T	0.32±0.1(0.013±0.004)
Tape width	W	12.0±0.2(0.472±0.008)
Reel width	W1	16.8±2.0(0.661±0.079)

NOTE:Devices are packde in accordance with EIA standard RS-481-A and specification given above.